# 74AHC1G17-Q100; 74AHCT1G17-Q100

# Single Schmitt trigger buffer

Rev. 2 — 12 January 2022

**Product data sheet** 

### 1. General description

The 74AHC1G17-Q100 and 74AHCT1G17-Q100 are single buffers with Schmitt-trigger inputs. Inputs are overvoltage tolerant. This feature allows the use of these devices as translators in mixed voltage environments.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 2.0 to 5.5 V
- Overvoltage tolerant inputs to 5.5 V
- · High noise immunity
- · CMOS low power dissipation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level A
- · Symmetrical output impedance
- Balanced propagation delays
- Input levels:
  - For 74AHC1G17-Q100: CMOS level
  - For 74AHCT1G17-Q100: TTL level
- SOT353-1 package option
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

# 3. Applications

- · Wave and pulse shapers
- Astable multivibrators
- Monostable multivibrators

# 4. Ordering information

#### **Table 1. Ordering information**

| Type number       | Package           |        |  |          |  |  |  |  |  |
|-------------------|-------------------|--------|--|----------|--|--|--|--|--|
|                   | Temperature range | Name   | Description                                | Version  |  |  |  |  |  |
| 74AHC1G17GW-Q100  | -40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; | SOT353-1 |  |  |  |  |  |
| 74AHCT1G17GW-Q100 |                   |        | 5 leads; body width 1.25 mm                |          |  |  |  |  |  |



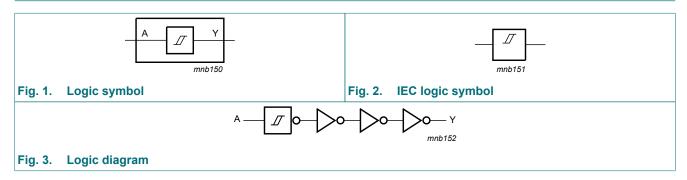
# 5. Marking

Table 2. Marking codes

| Type number       | Marking code[1] |
|-------------------|-----------------|
| 74AHC1G17GW-Q100  | AJ              |
| 74AHCT1G17GW-Q100 | Cl              |

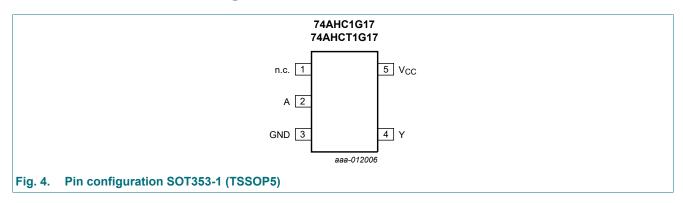
<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 6. Functional diagram



# 7. Pinning information

### 7.1. Pinning



### 7.2. Pin description

Table 3. Pin description

| Symbol | Pin              | Description   |
|--------|------------------|---------------|
| n.c.   | 1                | not connected |
| A      | 2                | data input    |
| GND    | 3                | ground (0 V)  |
| Υ      | 4                | data output   |
| Vcc    | 5 supply voltage |               |

# 8. Functional description

#### **Table 4. Function table**

H = HIGH voltage level; L = LOW voltage level

| Input | Output |
|-------|--------|
| A     | Υ      |
| L     | L      |
| Н     | Н      |

# 9. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions  |     | Min  | Max  | Unit |
|------------------|-------------------------|---|-----|------|------|------|
| V <sub>CC</sub>  | supply voltage          |   |     | -0.5 | +7.0 | V    |
| VI               | input voltage           |   |     | -0.5 | +7.0 | V    |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < -0.5 V   |     | -20  | -    | mA   |
| I <sub>OK</sub>  | output clamping current | $V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$                   | [1] | -    | ±20  | mA   |
| Io               | output current          | $-0.5 \text{ V} < \text{V}_{\text{O}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$ |     | -    | ±25  | mA   |
| I <sub>CC</sub>  | supply current          |   |     | -    | 75   | mA   |
| I <sub>GND</sub> | ground current          |   |     | -75  | -    | mA   |
| T <sub>stg</sub> | storage temperature     |   |     | -65  | +150 | °C   |
| P <sub>tot</sub> | total power dissipation | T <sub>amb</sub> = -40 °C to +125 °C  | [2] | -    | 250  | mW   |

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

# 10. Recommended operating conditions

### Table 6. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter           | Conditions | 74AHC1G17-Q100 |     |                 | 74AH | Unit |                 |    |
|------------------|---------------------|------------|----------------|-----|-----------------|------|------|-----------------|----|
|                  |                     |            | Min            | Тур | Max             | Min  | Тур  | Max             |    |
| V <sub>CC</sub>  | supply voltage      |            | 2.0            | 5.0 | 5.5             | 4.5  | 5.0  | 5.5             | V  |
| VI               | input voltage       |            | 0              | -   | 5.5             | 0    | -    | 5.5             | V  |
| Vo               | output voltage      |            | 0              | -   | V <sub>CC</sub> | 0    | -    | V <sub>CC</sub> | V  |
| T <sub>amb</sub> | ambient temperature |            | -40            | +25 | +125            | -40  | +25  | +125            | °C |

<sup>[2]</sup> For SOT353-1 (TSSOP5) package: P<sub>tot</sub> derates linearly with 3.3 mW/K above 74 °C.

# 11. Static characteristics

### **Table 7. Static characteristics**

Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter                 | Conditions   |      | 25 °C |      | -40 °C to +85 °C |      | -40 °C to +125 °C |      | Unit |
|------------------|---------------------------|--|------|-------|------|------------------|------|-------------------|------|------|
|                  |                           |  | Min  | Тур   | Max  | Min              | Max  | Min               | Max  |      |
| 74AHC1           | G17-Q100                  |  |      |       |      |                  |      |                   |      |      |
| V <sub>OH</sub>  | HIGH-level                | $V_I = V_{T+}$ or $V_{T-}$   |      |       |      |                  |      |                   |      |      |
|                  | output voltage            | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 2.0 V   | 1.9  | 2.0   | -    | 1.9              | -    | 1.9               | -    | V    |
|                  |                           | $I_O = -50 \mu A; V_{CC} = 3.0 V$  | 2.9  | 3.0   | -    | 2.9              | -    | 2.9               | -    | V    |
|                  |                           | I <sub>O</sub> = -50 μA; V <sub>CC</sub> = 4.5 V   | 4.4  | 4.5   | -    | 4.4              | -    | 4.4               | -    | V    |
|                  |                           | $I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$  | 2.58 | -     | -    | 2.48             | -    | 2.40              | -    | V    |
|                  |                           | $I_O = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$  | 3.94 | -     | -    | 3.8              | -    | 3.70              | -    | V    |
| V <sub>OL</sub>  | LOW-level                 | $V_I = V_{T+}$ or $V_{T-}$   |      |       |      |                  |      |                   |      |      |
|                  | output voltage            | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 2.0 V  | -    | 0     | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                  |                           | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 3.0 V  | -    | 0     | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                  |                           | I <sub>O</sub> = 50 μA; V <sub>CC</sub> = 4.5 V  | -    | 0     | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                  |                           | I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V   | -    | -     | 0.36 | -                | 0.44 | -                 | 0.55 | V    |
|                  |                           | $I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$   | -    | -     | 0.36 | -                | 0.44 | -                 | 0.55 | V    |
| I <sub>I</sub>   | input leakage<br>current  | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V   | -    | -     | 0.1  | -                | 1.0  | -                 | 2.0  | μΑ   |
| I <sub>CC</sub>  | supply current            | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$  | -    | -     | 1.0  | -                | 10   | -                 | 40   | μΑ   |
| Cı               | input<br>capacitance      |  | -    | 1.5   | 10   | -                | 10   | -                 | 10   | pF   |
| 74AHCT           | 1G17-Q100                 |  | ı    |       |      | I                |      | '                 | 1    |      |
| V <sub>OH</sub>  | HIGH-level                | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$  |      |       |      |                  |      |                   |      |      |
|                  | output voltage            | I <sub>O</sub> = -50 μA  | 4.4  | 4.5   | -    | 4.4              | -    | 4.4               | -    | V    |
|                  |                           | I <sub>O</sub> = -8.0 mA   | 3.94 | -     | -    | 3.8              | -    | 3.70              | -    | V    |
| V <sub>OL</sub>  | LOW-level                 | $V_{I} = V_{T+} \text{ or } V_{T-}; V_{CC} = 4.5 \text{ V}$  |      |       |      |                  |      |                   |      |      |
|                  | output voltage            | I <sub>O</sub> = 50 μA   | -    | 0     | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                  |                           | I <sub>O</sub> = 8.0 mA  | -    | -     | 0.36 | -                | 0.44 | -                 | 0.55 | V    |
| l <sub>l</sub>   | input leakage<br>current  | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V   | -    | -     | 0.1  | -                | 1.0  | -                 | 2.0  | μΑ   |
| I <sub>CC</sub>  | supply current            | $V_I = V_{CC}$ or GND; $I_O = 0$ A;<br>$V_{CC} = 5.5 \text{ V}$  | -    | -     | 1.0  | -                | 10   | -                 | 40   | μΑ   |
| Δl <sub>CC</sub> | additional supply current | per input pin; $V_I = 3.4 \text{ V}$ ;<br>other inputs at $V_{CC}$ or GND;<br>$I_O = 0 \text{ A}$ ; $V_{CC} = 5.5 \text{ V}$ | -    | -     | 1.35 | -                | 1.5  | -                 | 1.5  | mA   |
| Cı               | input<br>capacitance      |  | -    | 1.5   | 10   | -                | 10   | -                 | 10   | pF   |

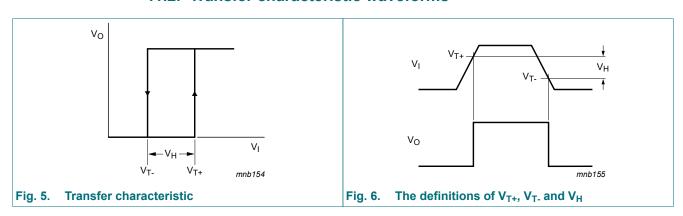
### 11.1. Transfer characteristics

**Table 8. Transfer characteristics** 

At recommended operating conditions; voltages are referenced to GND (ground = 0 V). See Fig. 5 and Fig. 6.

| Symbol          | Parameter                     | Conditions              |      | 25 °C |      | -40 °C to | o +85 °C | -40 °C to | +125 °C | Unit |
|-----------------|-------------------------------|-------------------------|------|-------|------|-----------|----------|-----------|---------|------|
|                 |                               |                         | Min  | Тур   | Max  | Min       | Max      | Min       | Max     |      |
| 74AHC1          | G17-Q100                      |                         |      |       |      |           |          |           |         |      |
| V <sub>T+</sub> | positive-going                | V <sub>CC</sub> = 3.0 V | -    | -     | 2.2  | -         | 2.2      | -         | 2.2     | V    |
|                 | threshold voltage             | V <sub>CC</sub> = 4.5 V | -    | -     | 3.15 | -         | 3.15     | -         | 3.15    | V    |
|                 | Voltage                       | V <sub>CC</sub> = 5.5 V | -    | -     | 3.85 | -         | 3.85     | -         | 3.85    | V    |
| V <sub>T-</sub> | negative-                     | V <sub>CC</sub> = 3.0 V | 0.9  | -     | -    | 0.9       | -        | 0.9       | -       | V    |
|                 | going<br>threshold            | V <sub>CC</sub> = 4.5 V | 1.35 | -     | -    | 1.35      | -        | 1.35      | -       | V    |
|                 | voltage                       | V <sub>CC</sub> = 5.5 V | 1.65 | -     | -    | 1.65      | -        | 1.65      | -       | V    |
| V <sub>H</sub>  | hysteresis                    | V <sub>CC</sub> = 3.0 V | 0.3  | -     | 1.2  | 0.3       | 1.2      | 0.25      | 1.2     | V    |
|                 | voltage                       | V <sub>CC</sub> = 4.5 V | 0.4  | -     | 1.4  | 0.4       | 1.4      | 0.35      | 1.4     | V    |
|                 |                               | V <sub>CC</sub> = 5.5 V | 0.5  | -     | 1.6  | 0.5       | 1.6      | 0.45      | 1.6     | V    |
| 74AHCT          | 1G17-Q100                     |                         |      |       |      |           |          |           |         |      |
| V <sub>T+</sub> | positive-going                | V <sub>CC</sub> = 4.5 V | -    | -     | 2.0  | -         | 2.0      | -         | 2.0     | V    |
|                 | threshold voltage             | V <sub>CC</sub> = 5.5 V | -    | -     | 2.0  | -         | 2.0      | -         | 2.0     | V    |
| V <sub>T-</sub> | negative-                     | V <sub>CC</sub> = 4.5 V | 0.5  | -     | -    | 0.5       | -        | 0.5       | -       | V    |
|                 | going<br>threshold<br>voltage | V <sub>CC</sub> = 5.5 V | 0.6  | -     | -    | 0.6       | -        | 0.6       | -       | V    |
| V <sub>H</sub>  | hysteresis                    | V <sub>CC</sub> = 4.5 V | 0.4  | -     | 1.4  | 0.4       | 1.4      | 0.35      | 1.4     | V    |
|                 | voltage                       | V <sub>CC</sub> = 5.5 V | 0.4  | -     | 1.6  | 0.4       | 1.6      | 0.35      | 1.6     | V    |

### 11.2. Transfer characteristic waveforms



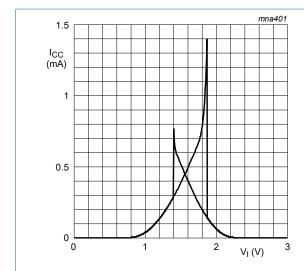


Fig. 7. Typical 74AHC1G17-Q100 transfer characteristics; V<sub>CC</sub> = 3.0 V

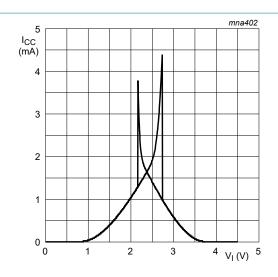


Fig. 8. Typical 74AHC1G17-Q100 transfer characteristics; V<sub>CC</sub> = 4.5 V

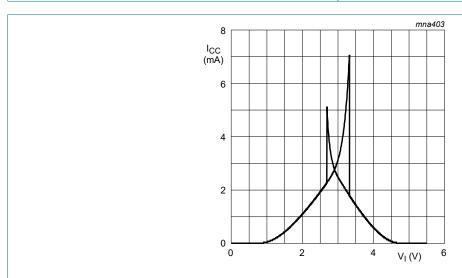


Fig. 9. Typical 74AHC1G17-Q100 transfer characteristics;  $V_{CC} = 5.5 \text{ V}$ 

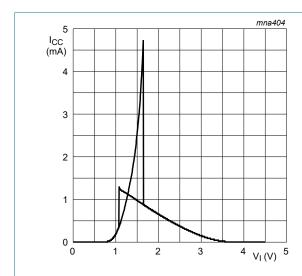


Fig. 10. Typical 74AHCT1G17-Q100 transfer characteristics; V<sub>CC</sub> = 4.5 V

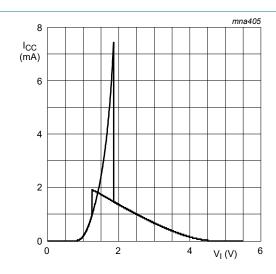


Fig. 11. Typical 74AHCT1G17-Q100 transfer characteristics; V<sub>CC</sub> = 5.5 V

# 12. Dynamic characteristics

#### **Table 9. Dynamic characteristics**

GND = 0 V;  $t_r = t_f \le 3.0$  ns. For waveform, see Fig. 12. For test circuit, see Fig. 13.

| Symbol          | Parameter                           | Conditions  |            |     | 25 °C |      | -40 °C t | o +85 °C | -40 °C to +125 °C |      | Unit |
|-----------------|-------------------------------------|---|------------|-----|-------|------|----------|----------|-------------------|------|------|
|                 |                                     |   |            | Min | Тур   | Max  | Min      | Max      | Min               | Max  |      |
| 74AHC1          | G17-Q100                            |   |            |     |       |      |          |          | ·                 | 1    |      |
|                 | propagation                         | A to Y  | [1]        |     |       |      |          |          |                   |      |      |
|                 | delay                               | V <sub>CC</sub> = 3.0 V to 3.6 V  | [2]        |     |       |      |          |          |                   |      |      |
|                 |                                     | C <sub>L</sub> = 15 pF  |            | -   | 4.2   | 12.8 | 1.0      | 15.0     | 1.0               | 16.5 | ns   |
|                 |                                     | C <sub>L</sub> = 50 pF  |            | -   | 6.0   | 16.3 | 1.0      | 18.5     | 1.0               | 20.5 | ns   |
|                 |                                     | V <sub>CC</sub> = 4.5 V to 5.5 V  | [3]        |     |       |      |          |          |                   |      |      |
|                 |                                     | C <sub>L</sub> = 15 pF  |            | -   | 3.2   | 8.6  | 1.0      | 10.0     | 1.0               | 11.0 | ns   |
|                 |                                     | C <sub>L</sub> = 50 pF  |            | -   | 4.6   | 10.6 | 1.0      | 12.0     | 1.0               | 13.5 | ns   |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | per buffer; $C_L = 50 \text{ pF}$ ;<br>f = 1 MHz; $V_I = \text{GND to } V_{CC}$           | [4]        | -   | 12    | -    | -        | -        | -                 | -    | pF   |
| 74AHCT          | 1G17-Q100                           |   |            |     |       |      |          |          |                   |      |      |
| t <sub>pd</sub> | propagation delay                   | A to Y<br>V <sub>CC</sub> = 4.5 V to 5.5 V  | [1]<br>[3] |     |       |      |          |          |                   |      |      |
|                 |                                     | C <sub>L</sub> = 15 pF  |            | -   | 4.1   | 7.0  | 1.0      | 8.0      | 1.0               | 9.0  | ns   |
|                 |                                     | C <sub>L</sub> = 50 pF  |            | -   | 5.9   | 8.5  | 1.0      | 10.0     | 1.0               | 11.0 | ns   |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | per buffer; C <sub>L</sub> = 50 pF;<br>f = 1 MHz; V <sub>I</sub> = GND to V <sub>CC</sub> | [4]        | -   | 13    | -    | -        | -        | -                 | -    | pF   |

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volt.

**Product data sheet** 

 $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ . Typical values are measured at  $V_{CC}$  = 3.3 V. Typical values are measured at  $V_{CC}$  = 5.0 V.

<sup>[4]</sup>  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu$ W).

### 12.1. Waveform and test circuit

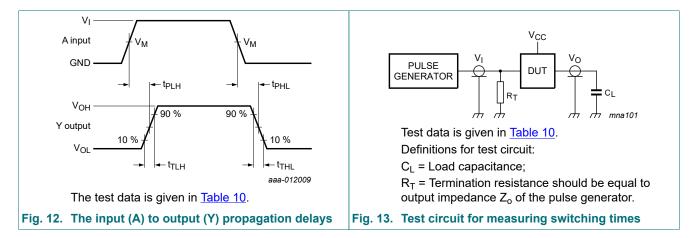


Table 10. Test data

| Table 141 Fot data |                        |                       |                       |  |  |  |  |  |
|--------------------|------------------------|-----------------------|-----------------------|--|--|--|--|--|
| Type number        | Input                  | Output                |                       |  |  |  |  |  |
|                    | V <sub>I</sub>         | V <sub>M</sub>        | V <sub>M</sub>        |  |  |  |  |  |
| 74AHC1G17-Q100     | GND to V <sub>CC</sub> | 0.5 × V <sub>CC</sub> | 0.5× V <sub>CC</sub>  |  |  |  |  |  |
| 74AHCT1G17-Q100    | GND to 3.0 V           | 1.5 V                 | 0.5 × V <sub>CC</sub> |  |  |  |  |  |

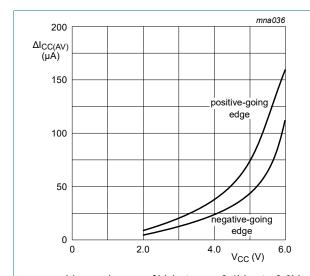
# 13. Application information

The slow input rise and fall times cause additional power dissipation, which can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$  where:

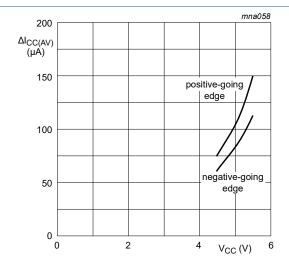
- P<sub>add</sub> = additional power dissipation (μW);
- f<sub>i</sub> = input frequency (MHz);
- t<sub>r</sub> = input rise time (ns); 10 % to 90 %;
- t<sub>f</sub> = input fall time (ns); 90 % to 10 %;
- $\Delta I_{CC(AV)}$  = average additional supply current ( $\mu A$ ).

Average additional  $I_{CC}$  differs with positive or negative input transitions, as shown in <u>Fig. 14</u> and Fig. 15.



Linear change of  $V_I$  between  $0.1 V_{CC}$  to  $0.9 V_{CC}$ 

Fig. 14. Average additional I<sub>CC</sub> for 74AHC1G17-Q100 Schmitt trigger devices



Linear change of V<sub>I</sub> between 0.1V<sub>CC</sub> to 0.9V<sub>CC</sub>

Fig. 15. Average additional I<sub>CC</sub> for 74AHCT1G17-Q100 Schmitt trigger devices

# 14. Package outline

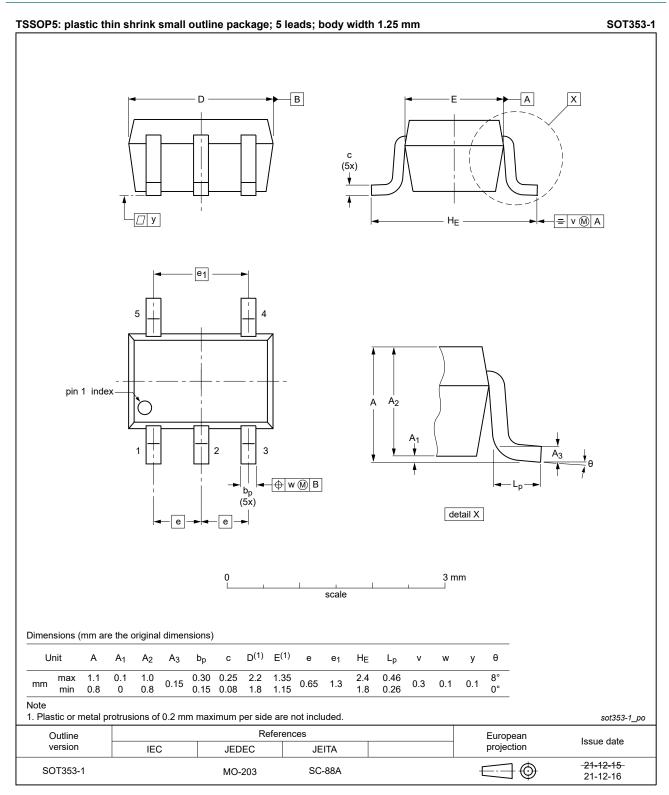


Fig. 16. Package outline SOT353-1 (TSSOP5)

### 15. Abbreviations

### **Table 11. Abbreviations**

| Acronym | Description                             |
|---------|---|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| НВМ     | Human Body Model                        |
| MIL     | Military                                |
| MM      | Machine Model                           |
| TTL     | Transistor-Transistor Logic             |

# 16. Revision history

### **Table 12. Revision history**

| Document ID             | Release date                                   | Data sheet status                    | Change notice   | Supersedes              |
|-------------------------|--|--------------------------------------|-----------------|-------------------------|
| 74AHC_AHCT1G17_Q100 v.2 | 20220112                                       | Product data sheet                   | -               | 74AHC_AHCT1G17_Q100 v.1 |
| Modifications:          | guidelines Legal texts Section 2 L Fig. 16: Pa | of Nexperia.<br>have been adapted to | the new company | ,                       |
| 74AHC_AHCT1G17_Q100 v.1 | 20160308                                       | Product data sheet                   | -               | -                       |

### 17. Legal information

#### **Data sheet status**

| Document status [1][2]         | Product<br>status [3] | Definition  |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet   | Development           | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification         | This document contains data from the preliminary specification.                       |
| Product [short]<br>data sheet  | Production            | This document contains the product specification.                                     |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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#### **Definitions**

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### **Contents**

| General description   | 1            |
|---|--------------|
| Features and benefits   | 1            |
| Applications  | 1            |
| Ordering information  | 1            |
| Marking   | 2            |
| Functional diagram  | 2            |
| Pinning information   | 2            |
| . Pinning   | 2            |
| Pin description   | 2            |
| Functional description  | 3            |
| Limiting values   | 3            |
| Recommended operating conditions  | 3            |
| Static characteristics  | 4            |
| Transfer characteristics  | 5            |
| Transfer characteristic waveforms   | 5            |
|   |              |
| Dynamic characteristics   | . 7          |
| Dynamic characteristics      Waveform and test circuit                      |              |
|   | 8            |
| 1. Waveform and test circuit  | 8<br>9       |
| 1. Waveform and test circuit  | 8<br>9<br>10 |
| Waveform and test circuit      Application information      Package outline | 8<br>9<br>10 |
|   | Applications |

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